

Product Summary

BV _{DSS}	Rds(on)	ID TA = +25°C
-50V	10Ω @ V _{GS} = -5V	-130mA

Description and Applications

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch

Features and Benefits

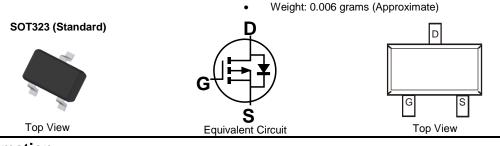
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
- https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>BSS84WQ</u>)

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208 Lead Free Plating (Matte Tin Finish Annealed over Alloy 42 Leadframe) (3)



Ordering Information (Note 4)

Part Number	Case	Packaging
BSS84W-7-F	SOT323 (Standard)	3,000 / Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

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Date Code Key	0007					0004						
Year	2007	•••	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	U		I	J	K	L	M	N	0	Р	R	S
				•								
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		Vdss	-50	V
Drain-Gate Voltage (Note 5)		Vdgr	-50	V
Gate-Source Voltage	Continuous	Vgss	±20	V
Drain Current (Note 5)	Continuous	lo	-130	mA
Pulsed Drain Current (Note 5)		Ідм	-1	A

Thermal Characteristics

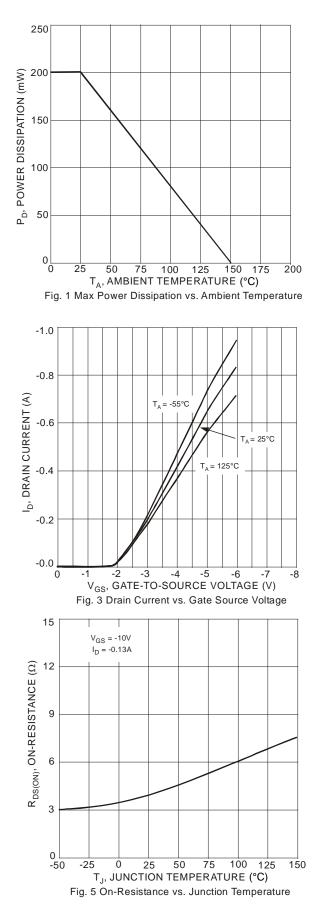
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient	Reja	625	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

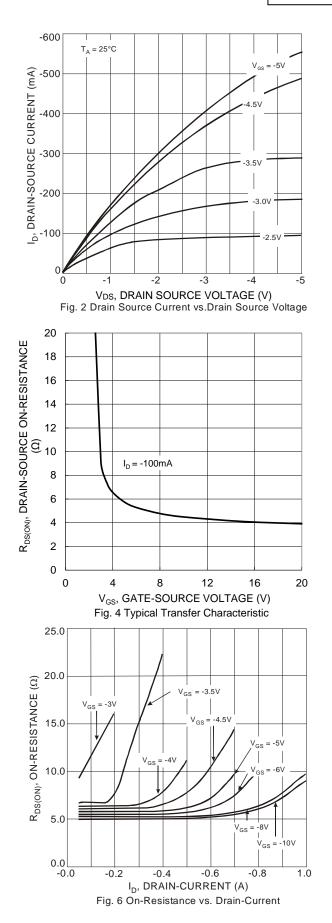
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						•
Drain-Source Breakdown Voltage	BV _{DSS}	-50	-75	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS			-1 -2 -100	μA μA nA	
Gate-Body Leakage	lgss	_		±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	VGS(TH)	-0.8	-1.6	-2.0	V	V _{DS} = V _{GS} , I _D = -1mA
Static Drain-Source On-Resistance	R _{DS(ON)}		6	10	Ω	$V_{GS} = -5V, I_D = -0.1A$
Forward Transconductance	g FS	0.05	_	_	S	V _{DS} = -25V, I _D = -0.1A
DYNAMIC CHARACTERISTICS (Note 7)						·
Input Capacitance	Ciss			45	pF	
Output Capacitance	Coss	_		25	pF	$V_{DS} = -25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	Crss	_	_	12	pF	
SWITCHING CHARACTERISTICS (Note 7)	•					
Turn-On Delay Time	td(on)	_	10		ns	$V_{DD} = -30V, I_D = -0.27A,$
Turn-Off Delay Time	t _{D(OFF)}	_	18	_	ns	$R_{GEN} = 50\Omega$, $V_{GS} = -10V$

Notes: 5. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Incorporated's suggested pad layout document, which Can be found on our website at http://www.diodes.com/package-outlines.html.
Short duration pulse test used to minimize self-heating effect.
Guarantee by design. Not subject to production testing.



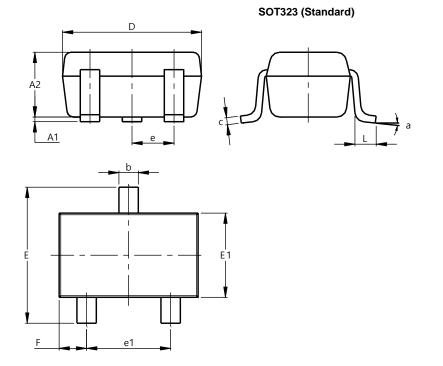






Package Outline Dimensions

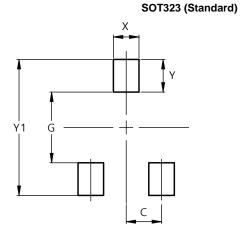
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323 (Standard)								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.80	1.00	0.90					
b	0.20	0.40	0.30					
С	0.08	0.18	0.13					
D	1.80	2.20	2.00					
E	2.00	2.45	2.225					
E1	1.15	1.35	1.25					
е			0.65					
e1	1.20	1.40	1.30					
F	0.25	0.475	0.3625					
L	0.25	0.46	0.355					
а	0°	8°						
All	All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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